Substitute for Form 14	440 A & B/DTO		<del>- , </del>	Com	Complete if Known		
Substitute for Porting	49 A & B/F 10			Application Number	Unknown		
INFO	RMATION	DISCLOS	SURE	· Confirmation Number	Unknown		
STAT	<b>TEMENT B</b>	Y APPLIC	CANT	Filing Date	July 10, 2003		
				First Named Inventor	Kazuhiko NAGANO, et al.		
(us	se as many shee	ts as necessa	ry)	Art Unit	Unknown		
				Examiner Name	Unknown		
Sheet	1	of	1	Attorney Docket Number	Q76484		

		•	U.S.	PATENT DOCUM	ENTS
Examiner Initials*	Cite No.¹	Document Nu	ımber	Publication Date MM-DD-YYYY	
		Number	Kind Code <sup>2</sup> (if known)		Name of Patentee or Applicant of Cited Document
1/4		US 2002/0090172	Al	07/11/2002	
DA		US 2003/0048819	Al	03/13/2003	
		US			
		US			
		US			<del></del>
]		US	+		<del></del>
		US			
		US			
		US			

			F	OREIGN PA	TENT DOCUMEN	ITS	
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date	Name of Patentée or	
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation <sup>6</sup>
				<b>‡</b>			
				<del></del>			<del></del>
							<del></del>
	<del></del>		<del> </del>	<del> </del>			<del></del>
	<del></del>		······································	1			<b> </b>

		OTHER ART - NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	fuclude name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation
M	•	SHUNJI NAKAMURA, ET AL./InGaN-Based Laser Diodes grown on GaN Substrates with a Fundamental Transverse Mode/Japanese Journal of Applied Physics Part 2 Letters, Vol. 37, 1998, pp. L1020-1022	Article

Examiner Signature	Muy	Date Considered	1117/05

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup>Applicant's unique citation designation number (optional). <sup>2</sup>See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or in the comment box of this document. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>3</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to indicate here if English language Translation is attached.